

FS10AS-3

High-Speed Switching Use Nch Power MOS FET

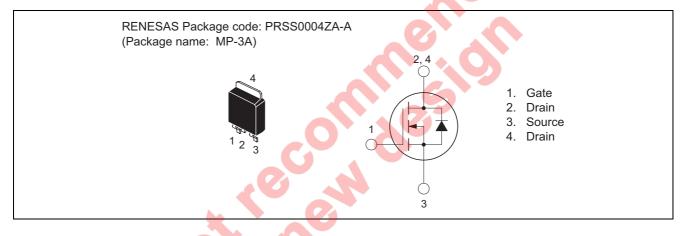
REJ03G1407-0200 (Previous: MEJ02G0111-0101) Rev.2.00 Aug 07, 2006

2500

Features

- Drive voltage : 10 V
- V_{DSS} : 150 V
- $r_{DS(ON) (max)}$: 170 m Ω
- I_D: 10 A
- Integrated Fast Recovery Diode (TYP.): 100 ns

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

		1	-	$(Tc = 25^{\circ}C)$	
Parameter	Symbol	Ratings	Unit	Conditions	
Drain-source voltage	V _{DSS}	150	V	$V_{GS} = 0 V$	
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$	
Drain current	I _D	10	А		
Drain current (Pulsed)	I _{DM}	40	А		
Avalanche drain current (Pulsed)	I _{DA}	10	А	L = 100 μH	
Source current	Is	10	А		
Source current (Pulsed)	I _{SM}	40	А		
Maximum power dissipation	PD	35	W		
Channel temperature	Tch	- 55 to +150	°C		
Storage temperature	Tstg	- 55 to +150	°C		
Mass	_	0.32	g	Typical value	



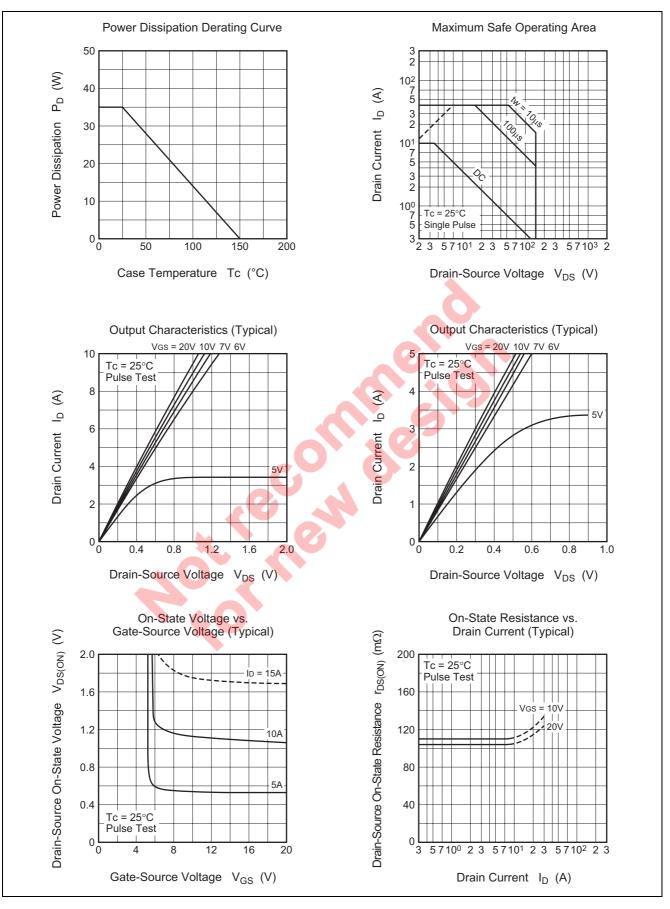
Electrical Characteristics

(Tch =	= 25°C)
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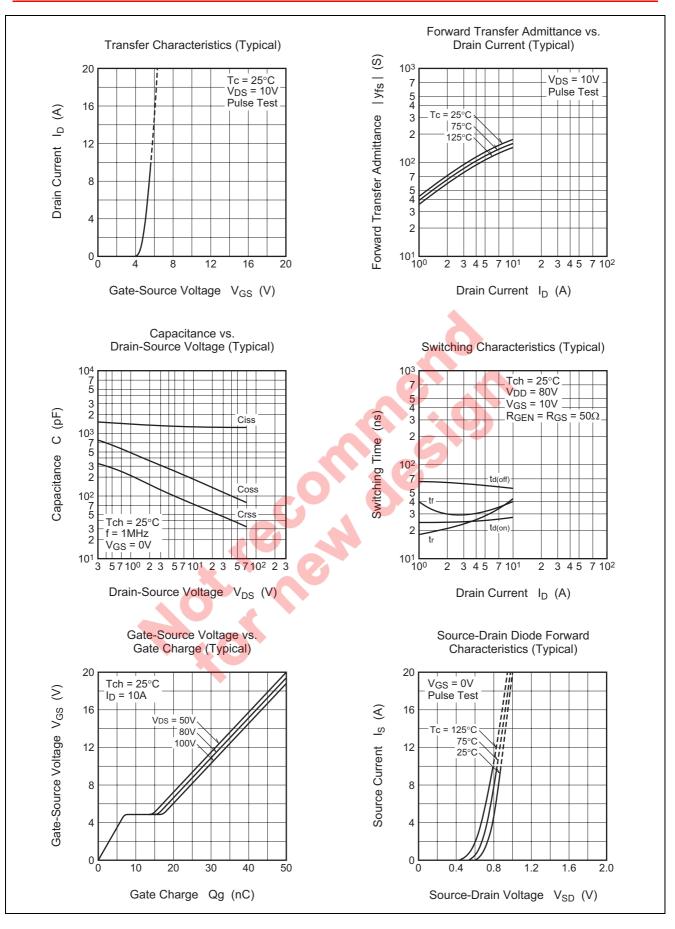
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions	
Drain-source breakdown voltage	V _{(BR)DSS}	150	—	—	V	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	
Gate-source leakage current	I _{GSS}	—	—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	
Drain-source leakage current	I _{DSS}		_	0.1	mA	$V_{DS} = 150 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	
Gate-source threshold voltage	V _{GS(th)}	2.0	3.0	4.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$	
Drain-source on-state resistance	r _{DS(ON)}		122	170	mΩ	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}$	
Drain-source on-state voltage	V _{DS(ON)}		0.61	0.85	V	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}$	
Forward transfer admittance	y _{fs}		12	_	S	$I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}$	
Input capacitance	Ciss		1250	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$	
Output capacitance	Coss		175	_	pF	f = 1MHz	
Reverse transfer capacitance	Crss	_	75	—	pF		
Turn-on delay time	t _{d(on)}	_	25	—	ns	$V_{DD} = 80 V, I_D = 5 A,$	
Rise time	tr	_	30	—	ns	V _{GS} = 10 V,	
Turn-off delay time	t _{d(off)}	_	60	—	ns	$R_{GEN} = R_{GS} = 50 \ \Omega$	
Fall time	t _f	_	34	—	ns		
Source-drain voltage	V _{SD}	—	1.0	1.5	V	$I_{S} = 5 \text{ A}, V_{GS} = 0 \text{ V}$	
Thermal resistance	R _{th(ch-c)}	_	—	3.57	°C/W	Channel to case	
Reverse recovery time	t _{rr}	_	100		ns	$J_{s} = 10 \text{ A}, d_{is}/d_{t} = -100 \text{ A}/\mu \text{s}$	

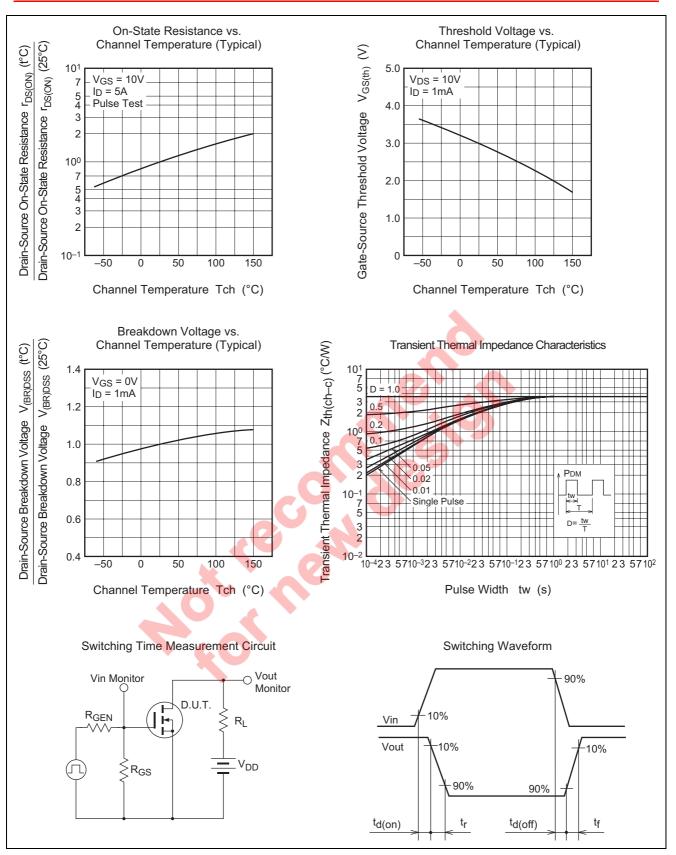


Performance Curves

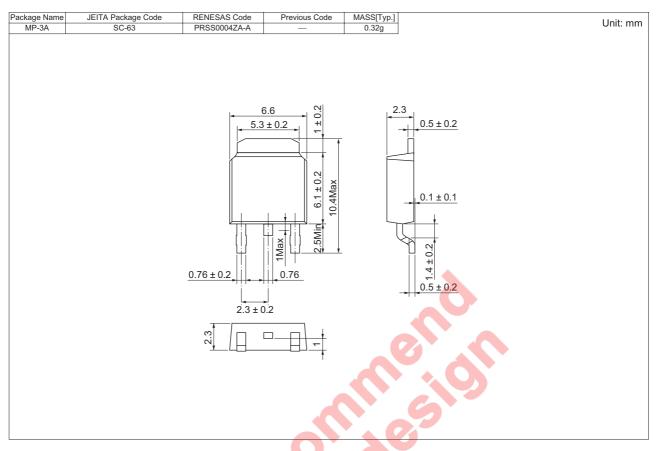








Package Dimensions



Order Code

Lead form	Standard packing	Qu	antity	Standard order code	Standard order code example
Surface-mounted type	Taping		3000	Type name – T +Direction (1 or 2) +3	FS10AS-3-T13
Surface-mounted type	Plastic Magazine (Tube)		75	Type name	FS10AS-3

Note: Please confirm the specification about the shipping in detail.

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